

FS5KM-10A

HIGH-SPEED SWITCHING USE

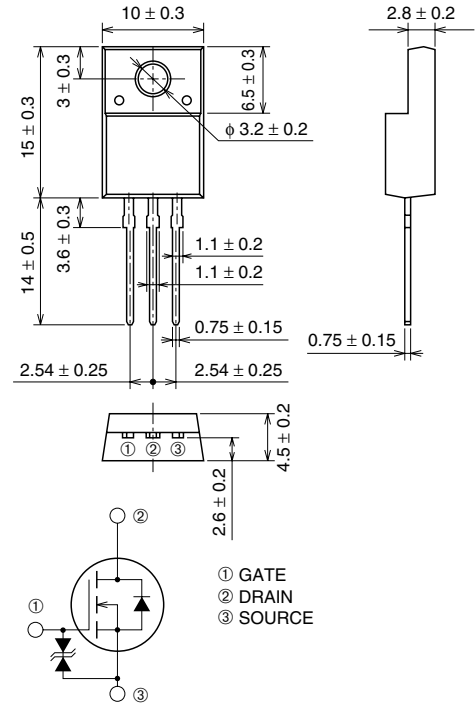
FS5KM-10A



- 10V DRIVE
- V_{DS} 500V
- $r_{DS(ON)}$ (MAX) 1.5Ω
- I_D 5A

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

SMPS, AC-adaptor, Power supply of Printer, Copier, TV, VCR. etc.

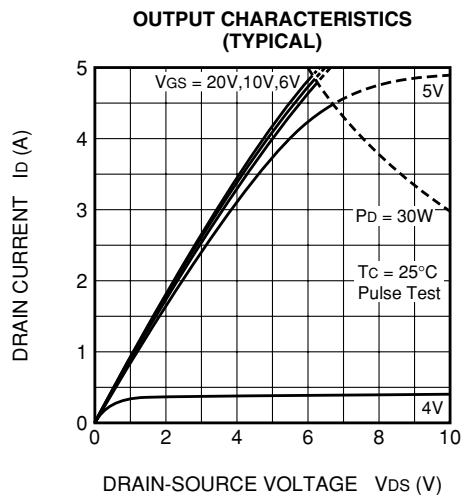
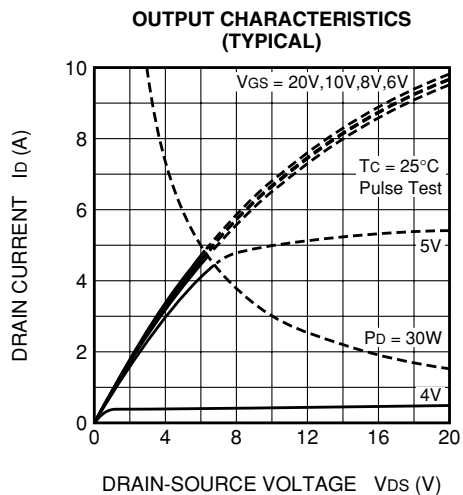
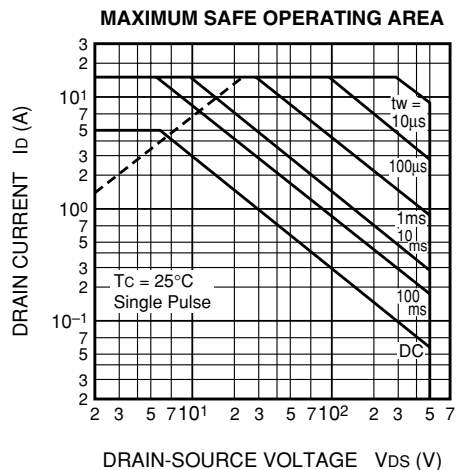
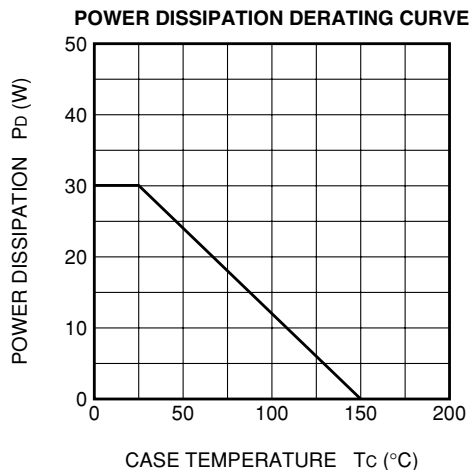
MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DS}	Drain-source voltage	$V_{GS} = 0V$	500	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 30	V
I_D	Drain current		5	A
I_{DM}	Drain current (Pulsed)		15	A
I_{DA}	Avalanche current (Pulsed)	$L = 200\mu H$	5	A
P_D	Maximum power dissipation		30	W
T_{ch}	Channel temperature		$-55 \sim +150$	°C
T_{stg}	Storage temperature		$-55 \sim +150$	°C
V_{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	V
—	Weight	Typical value	2.0	g

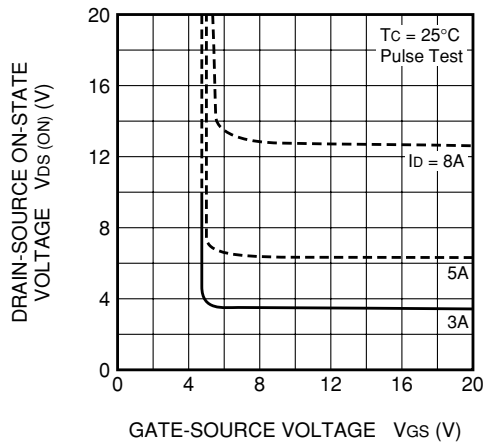
ELECTRICAL CHARACTERISTICS ($T_{ch} = 25^{\circ}\text{C}$)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$	500	—	—	V
$V_{(BR)GSS}$	Gate-source breakdown voltage	$I_{GS} = \pm 100\mu\text{A}$, $V_{DS} = 0\text{V}$	± 30	—	—	V
I_{GSS}	Gate-source leakage current	$V_{GS} = \pm 25\text{V}$, $V_{DS} = 0\text{V}$	—	—	± 10	μA
I_{DSS}	Drain-source leakage current	$V_{DS} = 500\text{V}$, $V_{GS} = 0\text{V}$	—	—	1.0	mA
$V_{GS(th)}$	Gate-source threshold voltage	$I_D = 1\text{mA}$, $V_{DS} = 10\text{V}$	2.5	3.0	3.5	V
$r_{DS(ON)}$	Drain-source on-state resistance	$I_D = 2\text{A}$, $V_{GS} = 10\text{V}$	—	1.2	1.5	Ω
$V_{DS(ON)}$	Drain-source on-state voltage	$I_D = 2\text{A}$, $V_{GS} = 10\text{V}$	—	2.4	3.0	V
$ y_{fs} $	Forward transfer admittance	$I_D = 2\text{A}$, $V_{DS} = 10\text{V}$	2.7	4.5	—	S
C_{iss}	Input capacitance	$V_{DS} = 25\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	—	700	—	pF
C_{oss}	Output capacitance		—	70	—	pF
C_{rss}	Reverse transfer capacitance		—	15	—	pF
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 200\text{V}$, $I_D = 2\text{A}$, $V_{GS} = 10\text{V}$, $R_{GEN} = R_{GS} = 50\Omega$	—	15	—	ns
t_r	Rise time		—	20	—	ns
$t_{d(off)}$	Turn-off delay time		—	90	—	ns
t_f	Fall time		—	30	—	ns
V_{SD}	Source-drain voltage	$I_S = 2\text{A}$, $V_{GS} = 0\text{V}$	—	1.5	2.0	V
$R_{th(ch-c)}$	Thermal resistance	Channel to case	—	—	4.17	$^{\circ}\text{C/W}$

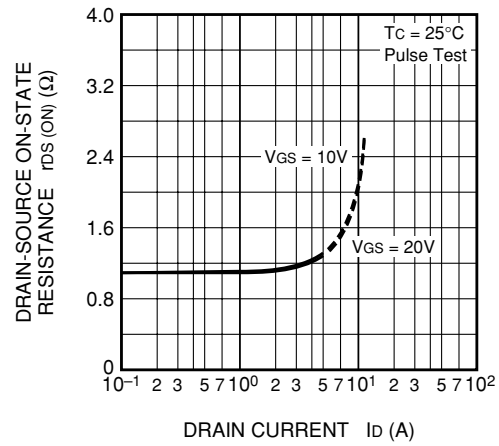
PERFORMANCE CURVES



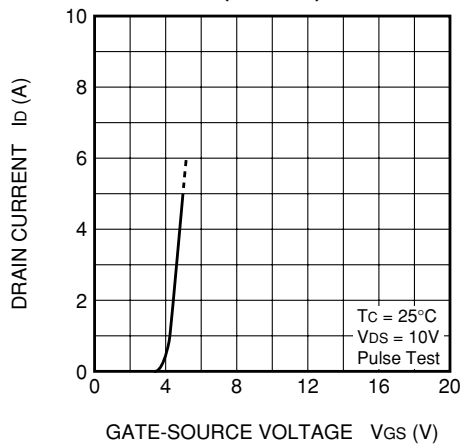
ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)



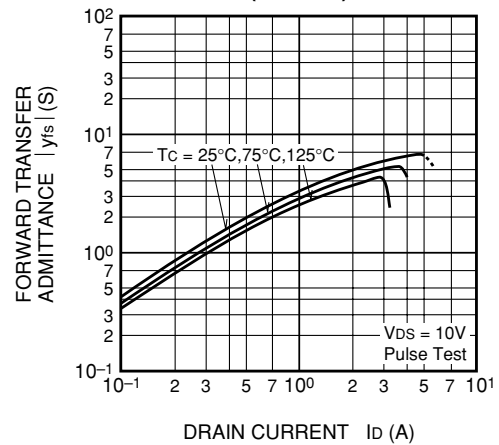
ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)



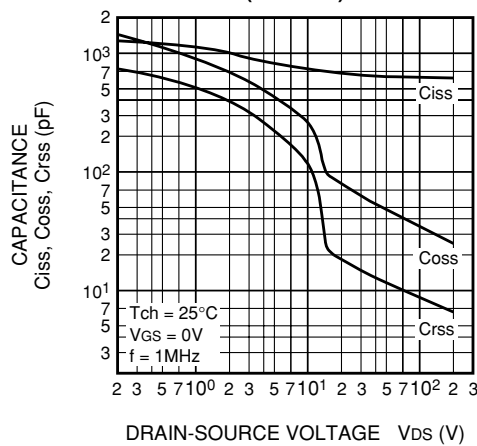
TRANSFER CHARACTERISTICS
(TYPICAL)



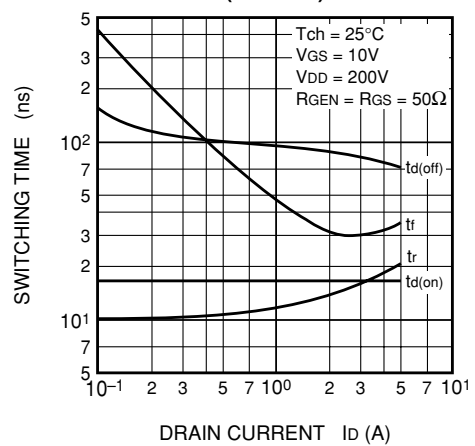
FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)

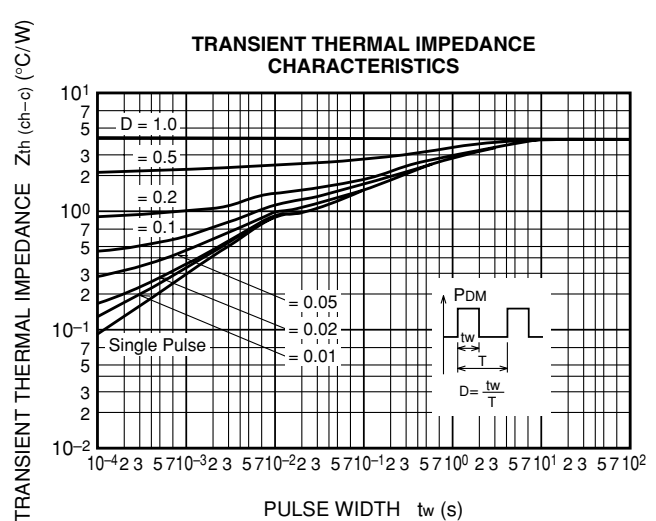
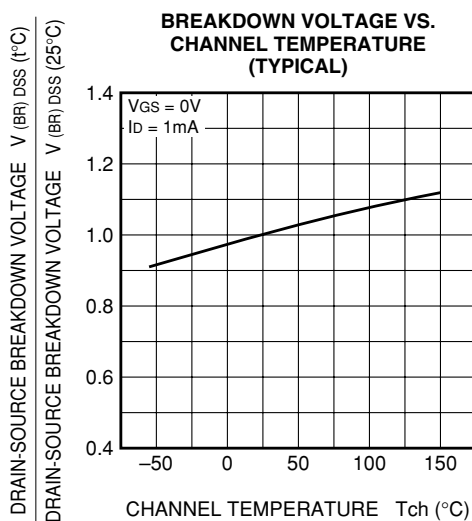
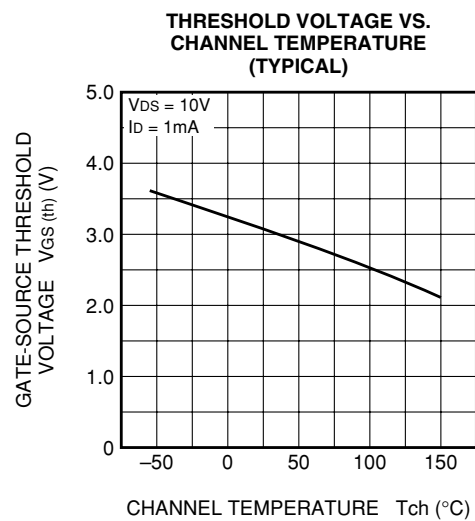
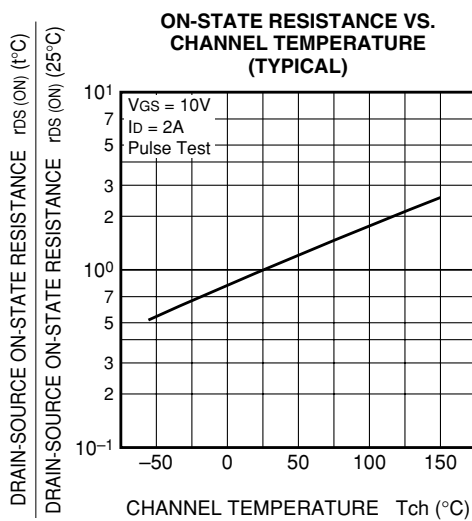
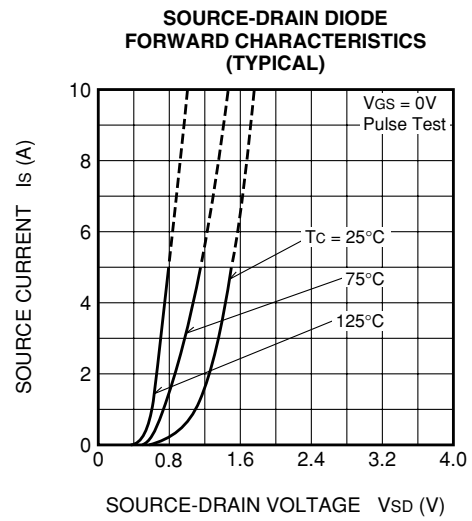
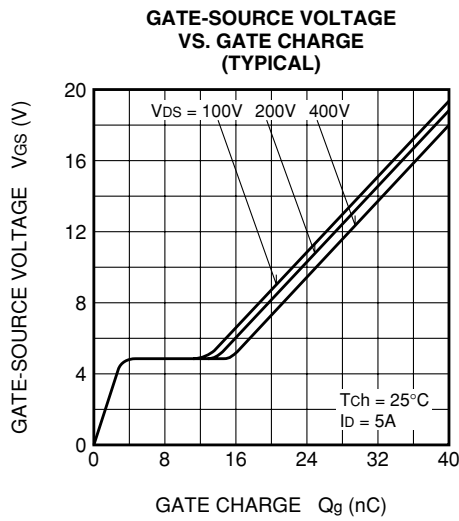


CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)



SWITCHING CHARACTERISTICS
(TYPICAL)





This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.